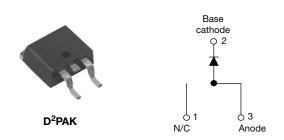
VS-10TQ035SPbF, VS-10TQ045SPbF

Vishay Semiconductors

www.vishay.com

High Performance Schottky Rectifier, 10 A



PRODUCT SUMMARY				
Package	D ² PAK			
I _{F(AV)}	10 A			
V _R	35 V, 40 V, 45 V			
V _F at I _F	0.57 V			
I _{RM}	15 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			
E _{AS}	13 mJ			

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-10TQ...SPbF Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	. CHARACTERISTICS VALUES UNITS						
I _{F(AV)}	Rectangular waveform	10	A				
V _{RRM}		35/45	V				
I _{FSM}	t _p = 5 μs sine	1050	A				
V _F	10 A _{pk} , T _J = 125 °C	0.49	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-10TQ035SPbF	VS-10TQ045SPbF	UNITS		
Maximum DC reverse voltage	V _R	35	45	V		
Maximum working peak reverse voltage	V _{RWM}	55	45	v		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 151 °C, rectangular waveform		10	А		
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	1050	А		
non-repetitive surge current I _{FSM} See fig. 7		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	280	~		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6.5 mH		13	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А		

Revision: 21-May-14

Document Number: 94121

1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS	
		10 A	T.I = 25 °C	0.57	V	
Maximum forward voltage drop	V (1)	20 A	1j=25 0	0.67		
See fig. 1	V _{FM} ⁽¹⁾	10 A	T _{.1} = 125 °C	0.49		
		20 A	1 _J = 125 C	0.61		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated V _B	2	mA	
See fig. 2	IRM (")	T _J = 125 °C	V _R = naleu V _R	15		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		900	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

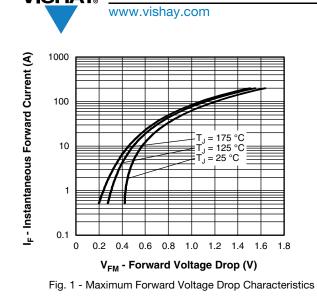
Note

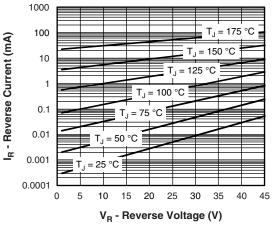
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-55 to +175	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4		°C/W	
Typical thermal resistance case to heatsink	9,	R _{thCS}	Mounting surface, smooth and greased 0.50		0,00	
Approvimate weight				2	g	
Approximate weight	Approximate weight			0.07	oz.	
Mounting torque				6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf \cdot in)	
Marking device Case style D ² PAK		10TQ	045S			

VS-10TQ035SPbF, VS-10TQ045SPbF









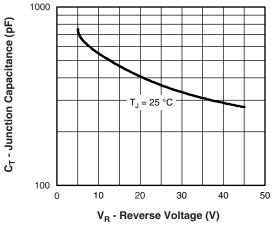


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

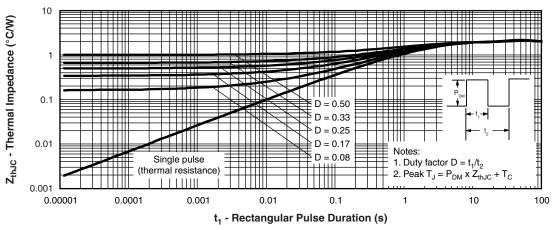
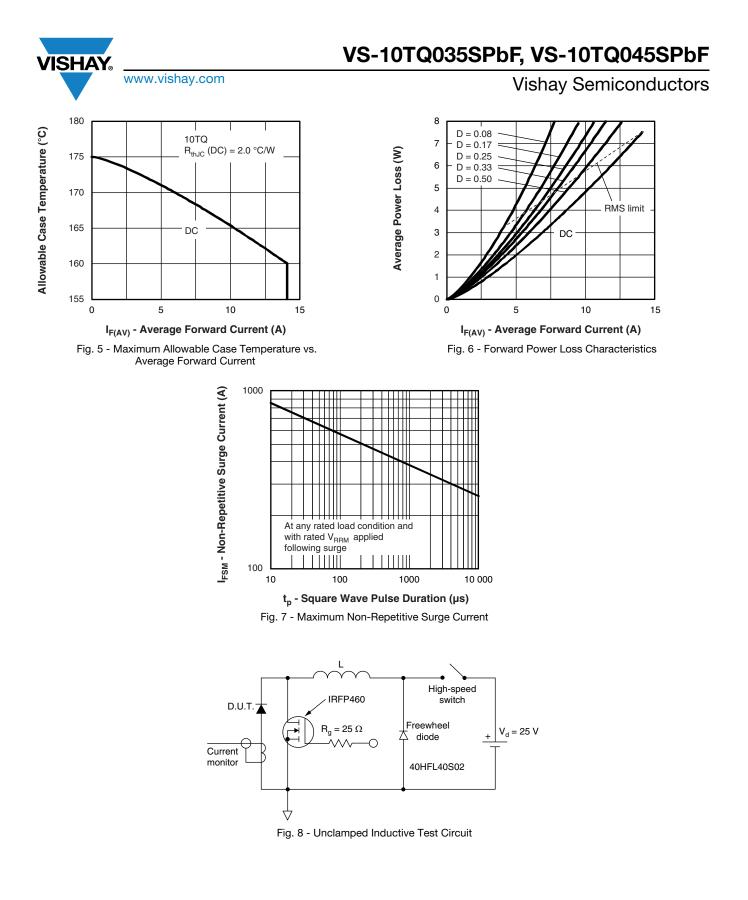


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Revision: 21-May-14

3

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

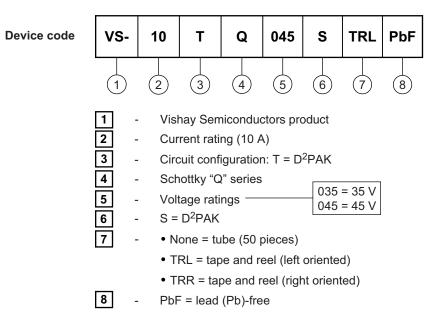




VS-10TQ035SPbF, VS-10TQ045SPbF

Vishay Semiconductors

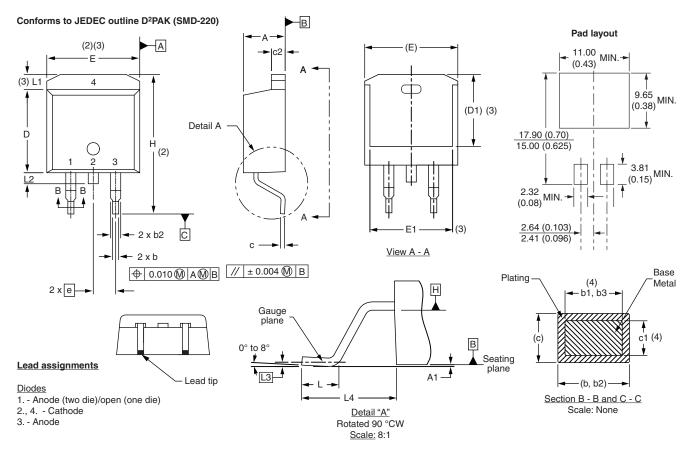
ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95014				
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			

Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

Notes

- $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

SYMBOL	MILLIMETERS INCHES		NOTES		
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NULES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

(7) Outline conforms to JEDEC outline TO-263AB

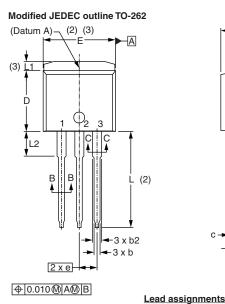
Outline Dimensions

Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches

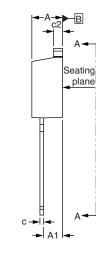


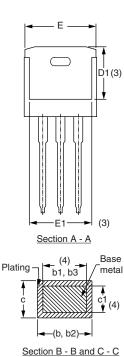
Lead tip

Diodes

3. - Anode

2., 4. - Cathode





Scale: None MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 4.06 4.83 0.160 0.190 А A1 2.03 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 0.51 0.89 0.020 0.035 4 b1 h2 1.14 1.78 0.045 0.070 b3 1.14 1.73 0.045 0.068 4 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 0.045 0.065 c2 1.65 D 8.51 9.65 0.335 0.380 2 0.270 D1 6.86 8.00 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 е 2.54 BSC 0.100 BSC L 13.46 14.10 0.530 0.555 L1 1.65 0.065 -3 L2 3.56 3.71 0.140 0.146 Notes

1. - Anode (two die)/open (one die)

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

www.vishay.com

For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com Document Number: 95014 Revision: 31-Mar-09

2



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

CUS06(TE85L,Q,M) D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR30H100MFST1G MMBD301M3T5G PMAD1103-LF PMAD1108-LF RB160M-50TR RB520S-30 RB551V-30 DD350N18K DZ435N40K DZ600N16K BAS16E6433HTMA1 BAS 3010S-02LRH E6327 BAT 54-02LRH E6327 IDL02G65C5XUMA1 NSR05F40QNXT5G JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SBAT54CWT1G SBM30-03-TR-E SK32A-LTP SK33A-TP SK34A-TP SK34B-TP SMD1200PL-TP ACDBN160-HF SS3003CH-TL-E STPS30S45CW PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MBR1240MFST1G MBRB30H30CT-1G BAS28E6433HTMA1 BAS 70-02L E6327 HSB123JTR-E JANTX1N5712-1 VS-STPS40L45CW-N3 DD350N12K SB007-03C-TB-E SB10015M-TL-E SB1003M3-TL-E E SK110-LTP SK154-TP SK32A-TP SK33B-TP